## NSN 5961-01-165-0452

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

## **Overall Height:**

0.360 inches

## **Overall Width:**

1.050 inches

#### **Mounting Facility Quantity:**

2

#### Internal Configuration:

#### Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### T0-3

Electrode Internally-electrically Connected To Case:

Drain

#### Mounting Method:

Unthreaded hole

#### **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

200.0 drain to source voltage and 200.0 drain to gate voltage

## **Current Rating Per Characteristic:**

36.00 amperes off-state current, peak

## **Power Rating Per Characteristic:**

75.0 watts total power dissipation

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Test Data Document:**

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 pin and 1 case

## **Specification Data:**

81349-mil-prf-19500/542 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

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Fiig: A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.

